



Zinc Oxide / Nanocrystalline Silicon Contacts for Silicon Heterojunction Solar Cells

Huimin Li

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Contents

Contents	I
Abstract.....	V
Zusammenfassung.....	VII
Chapter 1 Introduction.....	1
Chapter 2 Fundamentals and literature review	5
2.1 Crystalline silicon solar cells.....	5
2.2 Silicon heterojunction solar cells	8
2.2.1 Conventional SHJ solar cells.....	9
2.2.2 Alternative Si thin-films and TCO materials in SHJ solar cells.....	10
2.3 SHJ solar cells with AZO and doped nc-Si.....	11
Chapter 3 SHJ solar cell fabrication and characterization methods	12
3.1 SHJ solar cell fabrication	12
3.1.1 Wafer cleaning.....	13
3.1.2 Silicon layer deposition	13
3.1.3 AZO sputtering	15
3.1.4 Metallization.....	15
3.1.5 Finished SHJ solar cells.....	16
3.2 Characterization methods	17
3.2.1 Material characterization methods.....	17
3.2.2 SHJ solar cell characterization methods	20
Chapter 4 Doped nc-Si and AZO for carrier selective contacts in SHJ solar cells.....	23
4.1 Doped nc-Si for SHJ solar cells	23
4.1.1 n-type nanocrystalline silicon layer.....	24
4.1.2 p-type nanocrystalline silicon layer.....	29
4.2 AZO for SHJ solar cells	31

Contents

4.2.1 AZO sputtered with varied pressures and power densities.....	32
4.2.2 AZO sputtered with varied heater temperatures, doping levels and gas precursor	36
4.3 Short summary	43
Chapter 5 AZO and doped nc-Si applied in SHJ solar cells.....	44
5.1 Optical and electrical properties of Si layers applied in SHJ solar cells.....	44
5.2 Implementation of AZO in SHJ solar cells	46
5.2.1 AZO sputtered at RT with 1 wt.% target in SHJ solar cells.....	46
5.2.2 AZO sputtered at elevated temperatures with 1 wt.% target in SHJ solar cells	53
5.2.3 AZO sputtered with varied doping levels and precursors in SHJ solar cells	55
5.2.4 Contact resistance at the interface between AZO and Si layer.....	58
5.2.5 Result summary for both 19 mm × 19 mm and M2 size SHJ solar cells	60
5.3 Short summary	63
Chapter 6 Influence of AZO sputtering in SHJ Solar Cells.....	65
6.1 Influence of AZO sputtering on the i/n and i/p symmetrical structures.....	66
6.1.1 Influence of AZO sputtering parameters on the i/n and i/p symmetrical structure	68
6.1.2 Influence of AZO sputtering on varied i/n symmetrical structure.....	73
6.2 Influence of AZO on SHJ solar cell precursors	76
6.3 Short summary	79
Chapter 7 Contacts at the interfaces between AZO and p-type Si layers	81
7.1 J-V characteristics for the SHJ solar cells with AZO and p-type Si layers.....	81
7.2 Analysis on the contact barrier between AZO and p-type nc-Si.....	83
7.3 Optimization on contact barrier between AZO and p-type nc-Si.....	85
7.3.1 Doping level, thickness, and seed layer in p-type nc-Si for contact barrier	85
7.3.2 Sputtering temperatures and doping concentrations in AZO for contact barrier	87
7.4 Short summary	89
Chapter 8 Loss analysis in SHJ solar cells.....	90
8.1 Theoretical limits for the SHJ solar cells	90
8.2 Loss analysis for the open circuit voltage of SHJ solar cells	91
8.3 Loss analysis for the fill factor of SHJ solar cells.....	93

8.4 Loss analysis for the series resistance of SHJ solar cells	97
8.5 Loss analysis for the short circuit current density of SHJ solar cells.....	102
8.6 Short summary	106
Chapter 9 Summary and outlook	107
9.1 Summary	107
9.2 Outlook.....	111
References	113
Abbreviations and symbols	123
Curriculum Vitae	132
List of Publications	133
Acknowledgements	134

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